

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Three-channel, Single-phase Power/Energy IC

Features

- Energy Linearity: ±0.1% of Reading over 1000:1 Dynamic Range
- On-chip Functions:
 - Voltage and Current Measurement
 - Active, Reactive, and Apparent Power/Energy
 - RMS Voltage and Current Calculations
 - Current Fault and Voltage Sag Detection
 - Calibration
 - Phase Compensation
 - Temperature Sensor
 - Energy Pulse Outputs
- Meets Accuracy Spec for IEC, ANSI, & JIS
- Low Power Consumption
- Tamper Detection and Correction
- Ground-referenced Inputs with Single Supply
- On-chip 2.5 V Reference (40 ppm / °C typ.)
- Power Supply Monitor Function
- Three-wire Serial Interface to Microcontroller or E²PROM
- Power Supply Configurations
 GND: 0 V, VA+: +5 V, VD+: +3.3 V to +5 V

Description

The CS5464 is a watt-hour meter on a chip. It measures line voltage and current and calculates active, reactive, apparent power, energy, power factor, and RMS voltage and current.

There are two separate inputs to measure line, ground, and/or neutral current enabling the meter to detect tampering and to continue operating. An internal RMS voltage reference can be used if voltage measurement is disabled by tampering.

Four $\Delta\Sigma$ analog-to-digital converters are used to measure voltage, two currents, and temperature.

The CS5464 is designed to interface to a variety of voltage and current sensors.

Additional features include system-level calibration, voltage sag and current fault detection, peak detection, phase compensation, and energy pulse outputs.

ORDERING INFORMATION

See Page 44.

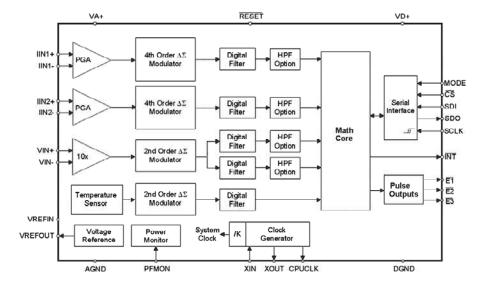




TABLE OF CONTENTS

1. Overview
Clock Generator 6 Control Pins and Serial Data I/O 6 Analog Inputs/Outputs 6 Power Connections 6 Other Pins 6
3. Characteristics & Specifications
Recommended Operating Conditions
Analog Characteristics7Accuracy7Analog Inputs (All Inputs)7Analog Inputs (Current Inputs)7Analog Inputs (Voltage Inputs)8Temperature8Power Supplies8
Voltage Reference
Digital Characteristics10Master Clock Characteristics10Filter Characteristics10Input/Output Characteristics10
Switching Characteristics 11 Start-up 11 Serial Port Timing 11 SDI Timing 11 SDO Timing 11 E2PROM mode Timing 11 E1, E2, and E3 Timing 13
Absolute Maximum Ratings
4. Signal Path Description 14 4.1 Analog-to-Digital Converters 14 4.2 Decimation Filters 14 4.3 Phase Compensation 14 4.4 DC Offset and Gain Correction 15 4.5 High-pass Filters 15 4.6 Low-Rate Calculations 15 4.7 RMS Results 15 4.8 Power and Energy Results 16 4.9 Peak Voltage and Current 16 4.10 Power Offset 16
5. Pin Descriptions 17 5.1 Analog Pins 17 5.1.1 Voltage Inputs 17 5.1.2 Current1 and Current2 Inputs 17 5.1.3 Power Fail Monitor Input 17



5.1.4 Voltage Reference Input	17
5.1.5 Voltage Reference Output	
5.1.6 Crystal Oscillator	
5.2 Digital Pins	
5.2.1 Reset Input	
5.2.2 CPU Clock Output	
5.2.3 Interrupt Output	
5.2.4 Energy Pulse Outputs	. <i>.</i> 17
5.2.5 Serial Interface	
6. Setting Up the CS5464	
6.1 Clock Divider	
6.2 CPU Clock Inversion	
6.3 Interrupt Pin Behavior	
6.4 Current Input Gain Ranges	
6.5 High-pass Filters	
6.6 Cycle Count	
6.7 Energy Pulse Outputs	
6.8 No Load Threshold	20
6.9 Energy Pulse Width	20
6.10 Energy Pulse Rate	20
6.11 Voltage Sag/Current Fault Detection	20
6.12 Epsilon	
6.13 Temperature Measurement	
7. Using the CS5464	
7.1 Initialization	
7.2 Power-down States	
7.3 Tamper Detection and Correction	22 22
7.5 Register Paging	
7.6 Commands	
8. Register Descriptions	
8.1 Page Register	
8.2 Page 0 Registers	
8.3 Page 1 Registers	
8.4 Page 2 Registers	38
9. System Calibration	39
9.1 Calibration	
9.1.1 Offset Calibration	
9.1.1.1 DC Offset Calibration	
9.1.1.2 AC Offset Calibration	
9.1.2 Gain Calibration	
9.1.2.1 AC Gain Calibration	
9.1.2.2 DC Gain Calibration	
9.1.3 Calibration Order	
orno cumpation craci and an arrangement of the contract of the	



9.1.4 Temperature Sensor Calibration	40
9.1.4.1 Temperature Offset Calibration	40
9.1.4.2 Temperature Gain Calibration	40
10. E2PROM Operation	
10.1 E ² PROM Configuration	41
10.2 E ² PROM Code	41
10.3 Which E ² PROMs Can Be Used?	
11. Basic Application Circuits	42
12. Package Dimensions	43
13. Ordering Information	44
14. Environmental, Manufacturing, & Handling Information	
15. Revision History	45
LIST OF F	IGURES
Figure 1. CS5464 Read and Write Timing Diagrams	. 12
Figure 2. Timing Diagram for $\overline{E1}$, $\overline{E2}$, and $\overline{E3}$. 13
Figure 3. Signal Flow for V1, I1, P1, Q1 Measurements	. 14
Figure 4. Signal Flow for V2, I2, P2, Q2 Measurements	. 14
Figure 5. Low-rate Calculations	. 16
Figure 6. Oscillator Connections	. 17
Figure 7. Sag and Fault Detect	. 21
Figure 8. Energy Channel Selection	. 22
Figure 9. Fixed RMS Voltage Selection	. 22
Figure 10. Calibration Data Flow	. 39
Figure 11. System Calibration of Offset	. 39
Figure 12. System Calibration of Gain.	. 40
Figure 13. Typical Interface of E ² PROM to CS5464	. 41
Figure 14. Typical Connection Diagram	. 42
	TABLES
Table 1. Interrupt Configuration	
Table 2. Current Input Gain Ranges	
Table 3. High-pass Filter Configuration	
Table 4. $\overline{\underline{E2}}$ Pin Configuration	
Table 5. E3 Pin Configuration	
Table 6. $\overline{\underline{E1}}$ / $\overline{E2}$ Modes	
Table 7. E3 Pin with E1MODE enabled	20



1. OVERVIEW

The CS5464 is a CMOS power measurement integrated circuit utilizing four $\Delta\Sigma$ analog-to-digital converters to measure line voltage, temperature, and current from up to two sources. It calculates active, reactive, and apparent power as well as RMS and peak voltage and current. It handles other system-related functions, such as pulse output conversion, voltage sag, current fault, voltage zero crossing, line frequency, and tamper detection.

The CS5464 is optimized to interface to current transformers or shunt resistors for current measurement, and to a resistive divider or voltage transformer for voltage measurement. Two full-scale ranges are provided on the current inputs to accommodate both types of current sensors. The second current channel can be used for tamper detection or as a second current input. The CS5464's three differential inputs have a common-mode input range from analog ground (AGND) to the positive analog supply (VA+).

An additional analog input (PFMON) is provided to allow the application to determine when a power failure is in progress. By monitoring the unregulated power supply, the application can take any required action when a power loss occurs.

An on-chip voltage reference (nominally 2.5 volts) is generated and provided at analog output, VREFOUT. This reference can be supplied to the chip by connecting it to the reference voltage input, VREFIN. Alternatively, an external voltage reference can be supplied to the reference input.

Three digital outputs $(\overline{E1}, \overline{E2}, \overline{E3})$ provide a variety of output signals and, depending on the mode selected, provide energy pulses, power failure indication, or other choices.

The CS5464 includes a three-wire serial host interface to an external microcontroller or serial E²PROM. Signals include serial data input (SDI), serial data output (SDO), serial clock (SCLK), and optionally, a chip select (CS), which allows the CS5464 to share the SDO signal with other devices. A MODE input is used to control whether an E²PROM will be used instead of a host microcontroller.



2. PIN DESCRIPTION

Crystal Out	хоит	1.	28	L	XIN	Crystal In
,		4 ' •	- 1	Г		Crystal In
CPU Clock Output	CPUCLK	□ 2	27	Þ	SDI	Serial Data Input
Positive Digital Supply	VD+	□ 3	26	þ	E2	Energy Output 2
Digital Ground	DGND	□ 4	25	Ь	Ē1	Energy Output 1
Serial Clock	SCLK	□ 5	24	þ	ĪNT	Interrupt
Serial Data Ouput	SDO	□ 6	23	þ	RESET	Reset
Chip Select	c s	□ 7	22	þ	E3	Energy Output 3
Mode Select	MODE	□ 8	21	þ	PFMON	Power Fail Monitor
Differential Voltage Input	VIN+	□ 9	20	þ	IIN1+	Differential Current Input
Differential Voltage Input	VIN-	□ 10	19	þ	IIN1-	Differential Current Input
Voltage Reference Output	VREFOUT	11	18	þ	VA+	Positive Analog Supply
Voltage Reference Input	VREFIN	□ 12	17	þ	AGND	Analog Ground
Factory Test	TEST1	□ 13	16	þ	IIN2+	Differential Current Input
Factory Test	TEST2	□ 14	15	þ	IIN2-	Differential Current Input

	,	The second of th
Clock Generator		
Crystal Out Crystal In	1,28	XOUT, XIN — Connect to an external quartz crystal. Alternatively, an external clock can be supplied to the XIN pin to provide the system clock for the device.
CPU Clock Output	2	CPUCLK - Logic-level output from crystal oscillator. Can be used to clock an external CPU.
Control Pins and Serial Da	ata I/O	
Serial Clock	5	SCLK — Clocks serial data from the SDI pin and to the SDO pin when $\overline{\text{CS}}$ is low. SCLK is a Schmitt-trigger input when MODE is low and a driven output when MODE is high.
Serial Data Output	6	SDO — Serial data output. Data is clocked out by SCLK.
Chip Select	7	CS — An input that enables the serial interface when MODE is low and a driven output when MODE is high.
Mode Select	8	$\label{eq:MODE-model} \textbf{MODE} - \textbf{High selects external E}^2 \textbf{PROM}, \textbf{Low selects external microcontroller}. \textbf{MODE includes a weak internal pull-down and therefore selects microcontroller mode if not connected.}$
Energy Outputs	22, 25, 26	E3, E1, E2 — Primarily active-low energy pulse outputs. These can be programmed to output other conditions.
Reset	23	RESET — An active-low Schmitt-trigger input used to reset the chip.
Interrupt	24	INT — Active-low output, indicates that an enabled condition has occurred.
Serial Data Input	27	SDI — Serial data input. Data is clocked in by SCLK.
Analog Inputs/Outputs		
Differential Voltage Inputs	9,10	VIN+, VIN- — Differential analog inputs for the voltage channel.
Differential Current Inputs	20,19, 16,15	IIN1+, IIN1-, IIN2+, IIN2- — Differential analog inputs for the current channels.
Power Fail Monitor	21	PFMON — Used to monitor the unregulated power supply via a resistive divider. If the PFMON voltage drops below its low limit, the low-supply detect (LSD) bit is set in the <i>Status</i> register.
Voltage Reference Output	11	VREFOUT — The on-chip voltage reference output. Nominally 2.5 V, referenced to AGND.
Voltage Reference Input	12	$\mbox{\it VREFIN}$ — The voltage reference input. Can be connected to VREFOUT or external 2.5 V reference.
Power Connections		
Positive Digital Supply	3	VD+ — The positive digital supply.
Digital Ground	4	DGND — Digital ground.
Positive Analog Supply	18	VA+ — The positive analog supply.
Analog Ground	17	AGND — Analog ground.
Other Pins		
Test1, Test2	13,14	NC — Factory use only. Connect to AGND.



3. CHARACTERISTICS & SPECIFICATIONS RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Тур	Max	Unit
Positive Digital Power Supply	VD+	3.135	5.0	5.25	V
Positive Analog Power Supply	VA+	4.75	5.0	5.25	V
Voltage Reference	VREFIN	-	2.5	-	V
Specified Temperature Range	T _A	-40	-	+85	°C

ANALOG CHARACTERISTICS

- Min / Max characteristics and specifications are guaranteed over all Recommended Operating Conditions.
- Typical characteristics and specifications are measured at nominal supply voltages and TA = 25 °C.
- VA+ = VD+ = 5 V ±5%; AGND = DGND = 0 V; VREFIN = +2.5 V. All voltages with respect to 0 V.
- DCLK = 4.096 MHz.

Param	eter	Symbol	Min	Тур	Max	Unit
Accuracy						1
Active Power (Note 1)	All Gain Ranges Input Range 0.1% - 100%	P _{Active}	-	±0.1	-	%
Reactive Power (Note 1 and 2)	All Gain Ranges Input Range 0.1% - 100%	Q_{Avg}	-	±0.2	-	%
Power Factor (Note 1 and 2)	All Gain Ranges Input Range 1.0% - 100% Input Range 0.1% - 1.0%	PF	-	±0.2 ±0.27		%
Current RMS (Note 1)	All Gain Ranges Input Range 1.0% - 100% Input Range 0.1% - 1.0%	I _{RMS}	-	±0.1 ±0.17		% % %
Voltage RMS (Note 1)	All Gain Ranges Input Range 5% - 100%	V _{RMS}	-	±0.1	-	%
Analog Inputs (All Inputs)						
Common Mode Rejection	(DC, 50, 60 Hz)	CMRR	80	-	-	dB
Common Mode + Signal			-0.25	-	VA+	V
Analog Inputs (Current Inputs	5)					
Differential Input Range [(IIN+) – (IIN-)]	(Gain = 10) (Gain = 50)	IIN	-	500 100	-	mV_{P-P} mV_{P-P}
Total Harmonic Distortion	(Gain = 50)	THD	80	94	-	dB
Crosstalk from Voltage Input at	Full Scale (50, 60 Hz)		-	-115	-	dB
Input Capacitance		IC	-	27	-	pF
Effective Input Impedance		EII	30	-	-	kΩ
Noise (Referred to Input)	(Gain = 10) (Gain = 50)	N _I	-	-	22.5 4.5	μV_{rms} μV_{rms}
Offset Drift (Without the High-pa	ass Filter)	OD	-	4.0	-	μV/°C
Gain Error	(Note 3)	GE	-	±0.4		%

Notes: 1. Applies when the HPF option is enabled.

2. Applies when the line frequency is equal to the product of the output word rate (OWR) and the value of *Epsilon*.



ANALOG CHARACTERISTICS (Continued)

Parameter	Symbol	Min	Тур	Max	Unit
Analog Inputs (Voltage Inputs)					
Differential Input Range [(VIN+) – (VIN-)]	VIN	-	500	-	mV_{P-P}
Total Harmonic Distortion	THD	65	75	-	dB
Crosstalk from Current Inputs at Full Scale (50, 60 Hz)		-	-70	-	dB
Input Capacitance All Gain Ranges	IC	-	2.0	-	pF
Effective Input Impedance	EII	2	-	-	MΩ
Noise (Referred to Input)	N _V	-	-	140	μV_{rms}
Offset Drift (Without the High-pass Filter)	OD	-	16.0	-	μV/°C
Gain Error (Note 3)	GE	-	±3.0		%
Temperature		•		•	•
Temperature Accuracy	T	-	±5	-	°C
Power Supplies					
Power Supply Currents (Active State) I _{A+}	PSCA	-	1.5	-	mA
$I_{D+}(VA+=VD+=5V)$	PSCD	-	3.5	-	mA
I_{D+} (VA+ = 5 V, VD+ = 3.3 V)	PSCD	-	2.3	-	mA
Power Consumption Active State (VA+ = VD+ = 5 V)		-	25	33	mW
(Note 4) Active State (VA + = 5 V, VD + = 3.3 V)	PC	-	15	20	mW
Stand-by State	10	-	7	-	mW
Sleep State		-	10	-	uW
Power Supply Rejection Ratio (50, 60 Hz)					
(Note 5) Voltage	PSRR	48	55	-	dB
Current (Gain = 50x)	1 01111	68	75	-	dB
Current (Gain = 10x)		60	65	-	dB
PFMON Low-voltage Trigger Threshold (Note 6)	PMLO	2.3	2.45	-	V
PFMON High-voltage Power-on Trip Point (Note 7)	PMHI	-	2.55	2.7	V

Notes: 3. Applies before system calibration.

- 4. All outputs unloaded. All inputs CMOS level.
- 5. Measurement method for PSRR: VREFIN tied to VREFOUT, VA+ = VD+ = 5 V, a 150 mV (zero-to-peak) (60 Hz) sinewave is imposed onto the +5 V DC supply voltage at VA+ and VD+ pins. The "+" and "-" input pins of both input channels are shorted to AGND. The CS5464 is then commanded to continuous conversion acquisition mode, and digital output data is collected for the channel under test. The (zero-to-peak) value of the digital sinusoidal output signal is determined, and this value is converted into the (zero-to-peak) value of the sinusoidal voltage (measured in mV) that would need to be applied at the channel's inputs, in order to cause the same digital sinusoidal output. This voltage is then defined as Veq. PSRR is (in dB):

$$PSRR = 20 \cdot log \left[\frac{150}{V_{eq}} \right]$$

- 6. When voltage level on PFMON is sagging, and LSD bit = 0, the voltage at which LSD is set to 1.
- 7. If the LSD bit has been set to 1 (because PFMON voltage fell below PMLO), this is the voltage level on PFMON at which the LSD bit can be permanently reset back to 0.



VOLTAGE REFERENCE

Parameter	Symbol	Min	Тур	Max	Unit
Reference Output					
Output Voltage	VREFOUT	+2.4	+2.5	+2.6	V
Temperature Coefficient (Note 8)	TC _{VREF}	-	40	-	ppm/°C
Load Regulation (Note 9)	ΔV_{R}	-	6	10	mV
Reference Input					
Input Voltage Range	VREFIN	+2.4	+2.5	+2.6	V
Input Capacitance		-	4	-	pF
Input CVF Current		-	100	-	nA

Notes: 8. The voltage at VREFOUT is measured across the temperature range. From these measurements the following formula is used to calculate the VREFOUT temperature coefficient:.

$$TC_{VREF} = \left(\frac{(VREFOUT_{MAX} - VREFOUT_{MIN})}{VREFOUT_{AVG}} \right) \left(\frac{1}{T_{A}^{MAX} - T_{A}^{MIN}} \right) \left(1.0 \times 10^6 \right)$$

9. Specified at maximum recommended output of 1 μ A, source or sink.



DIGITAL CHARACTERISTICS

- Min / Max characteristics and specifications are guaranteed over all Recommended Operating Conditions.
- Typical characteristics and specifications are measured at nominal supply voltages and TA = 25 °C.
- $VA+ = VD+ = 5V \pm 5\%$; AGND = DGND = 0 V. All voltages with respect to 0 V.
- DCLK = 4.096 MHz.

Parameter	Symbol	Min	Тур	Max	Unit
Master Clock Characteristics	.				
Master Clock Frequency Internal Gate Oscillator (Note 1	1) DCLK	2.5	4.096	20	MHz
Master Clock Duty Cycle		40	-	60	%
CPUCLK Duty Cycle (Note 12 and 1	3)	40	-	60	%
Filter Characteristics					
Phase Compensation Range (60 Hz, OWR = 4000 H	z)	-5.4	-	+5.4	0
Input Sampling Rate DCLK = MCLK	K	-	DCLK/8	-	Hz
Digital Filter Output Word Rate (Both channel	s) OWR	-	DCLK/1024	-	Hz
High-pass Filter Corner Frequency -3 c	В	-	0.5	-	Hz
Full-scale DC Calibration Range (Referred to Input) (Note 1	4) FSCR	25	-	100	%FS
Channel-to-channel Time-shift Error (Note 1	5)		1.0		μs
Input/Output Characteristics					
High-level Input Voltage All Pins Except XIN and SCLK and RESI X SCLK and RESI Low-level Input Voltage (VD = 5 V) All Pins Except XIN and SCLK and RESI	N VIH	0.6 VD+ (VD+) - 0.5 0.8 VD+	- - -	- - - 0.8	V V V
SCLK and RESI	V _{IL}	-	-	1.5 0.2 VD+	V V
Low-level Input Voltage (VD = 3.3 V) All Pins Except XIN and SCLK and RESI X SCLK and RESE	$_{\rm N}$ $_{\rm IL}$	- - -	- - -	0.48 0.3 0.2 VD+	V V V
High-level Output Voltage I _{out} = +5 m	a V _{OH}	(VD+) - 1.0	-	-	V
Low-level Output Voltage $I_{out} = -5 \text{ mA (VD} = +5 \\ I_{out} = -2.5 \text{ mA (VD} = +3.3 \\ I_{out} = -2.5 \text{ mA (VD} = -2.5 \text{ mA (VD} = +3.3 \\ I_{out} = -2.5 \text{ mA (VD} = -2$	V) V _{OL}		-	0.4 0.4	V
Input Leakage Current (Note 1	6) l _{in}	-	±1	±10	μΑ
3-state Leakage Current	I _{OZ}	-	-	±10	μΑ
Digital Output Pin Capacitance	C _{out}	-	5	-	рF

Notes: 10. All measurements performed under static conditions.

- 11. If a crystal is used, XIN frequency must remain between 2.5 MHz 5.0 MHz. If an external oscillator is used, XIN frequency range is 2.5 MHz 20 MHz, but K must be set so that MCLK is between 2.5 MHz 5.0 MHz.
- 12. If external MCLK is used, the duty cycle must be between 45% and 55% to maintain this specification.
- 13. The frequency of CPUCLK is equal to MCLK.
- 14. The minimum FSCR is limited by the maximum allowed gain register value. The maximum FSCR is limited by the full-scale signal applied to the input.
- 15. Configuration register (Config) bits PC[6:0] are set to "0000000".
- 16. The MODE pin is pulled low by an internal resistor.



SWITCHING CHARACTERISTICS

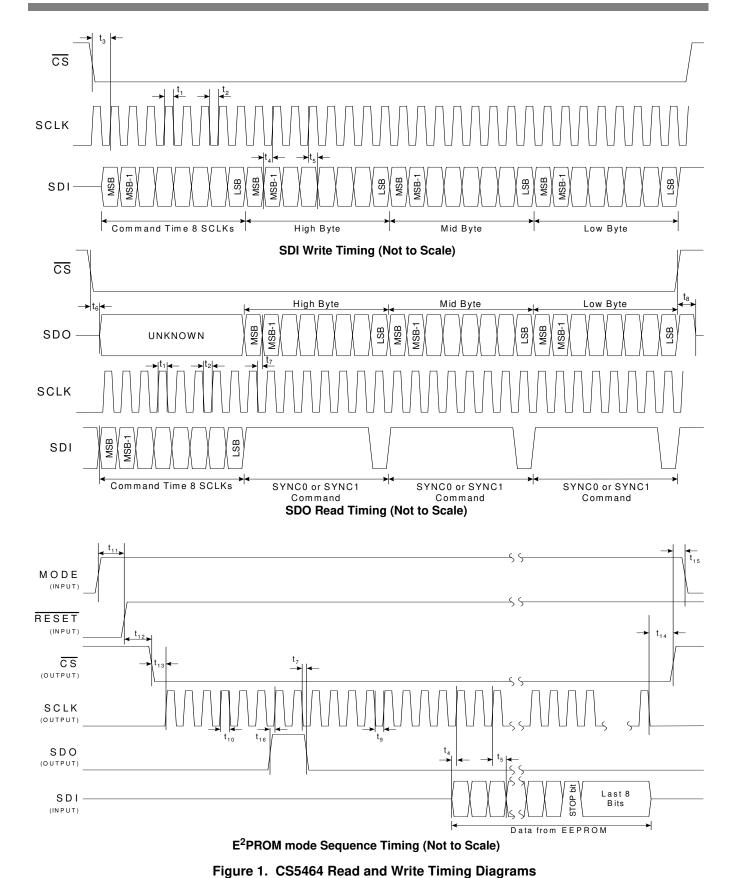
- Min / Max characteristics and specifications are guaranteed over all Recommended Operating Conditions.
- Typical characteristics and specifications are measured at nominal supply voltages and TA = 25 °C.
- $VA+ = 5 V \pm 5\% VD+ = 3.3 V \pm 5\%$ or $5 V \pm 5\%$; AGND = DGND = 0 V. All voltages with respect to 0 V.
- Logic Levels: Logic 0 = 0 V, Logic 1 = VD+.

Paramete	er	Symbol	Min	Тур	Max	Unit
Rise Times (Note 17)	Any Digital Output	t _{rise}	-	- 50	1.0	μs ns
Fall Times (Note 17)	Any Digital Output	t _{fall}	-	- 50	1.0	μs ns
Start-up			1	1	1	1
Oscillator Start-up Time	XTAL = 4.096 MHz (Note 11)	t _{ost}	-	60	-	ms
Serial Port Timing	,					_
Serial Clock Frequency		SCLK	-	-	2	MHz
Serial Clock	Pulse Width High Pulse Width Low	t ₁ t ₂	200 200	-	-	ns ns
SDI Timing						
CS Falling to SCLK Rising		t ₃	50	-	-	ns
Data Set-up Time Prior to SCLK Ri	sing	t ₄	50	-	-	ns
Data Hold Time After SCLK Rising		t ₅	100	-	-	ns
SDO Timing						
CS Falling to SDO Driving		t ₆	-	20	50	ns
SCLK Falling to New Data Bit (hold	d time)	t ₇	-	20	50	ns
CS Rising to SDO Hi-Z		t ₈	-	20	50	ns
E ² PROM mode Timing						
Serial Clock	Pulse Width Low Pulse Width High	t ₉ t ₁₀		8 8		DCLK DCLK
MODE setup time to RESET Rising	9	t ₁₁	50			ns
RESET rising to CS falling		t ₁₂	48			DCLK
CS falling to SCLK rising		t ₁₃	100	8		DCLK
SCLK falling to CS rising		t ₁₄		16		DCLK
CS rising to driving MODE low		t ₁₅	50			ns
SDO setup time to SCLK rising		t ₁₆	100			ns

Notes: 17. Specified using 10% and 90% points on waveform of interest. Output loaded with 50 pF.

18. Oscillator start-up time varies with crystal parameters. This specification does not apply when using an external clock source.







SWITCHING CHARACTERISTICS (Continued)

Parameter	Symbol	Min	Тур	Max	Unit
E1, E2, and E3 Timing (Note 19 and 20)					
Period	t _{period}	500	-	-	μS
Pulse Width	t _{pw}	244	-	-	μS
Rising Edge to Falling Edge	t ₃	6	-	-	μS
E2 Setup to E1 and/or E3 Falling Edge	t ₄	1.5	-	-	μS
E1 Falling Edge to E3 Falling Edge	t ₅	248	-	-	μS

Notes: 19. Pulse output timing is specified at DCLK = 4.096 MHz, E2MODE = 0, and E3MODE[1:0] = 0. Refer to 6.7 *Energy Pulse Outputs* on page 19 for more information on pulse output pins.

20. Timing is proportional to the frequency of DCLK.

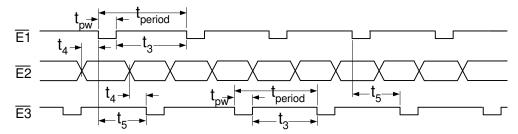


Figure 2. Timing Diagram for $\overline{E1}$, $\overline{E2}$, and $\overline{E3}$

ABSOLUTE MAXIMUM RATINGS

WARNING: Operation at or beyond these limits may result in permanent damage to the device.

Normal operation is not guaranteed at these extremes.

Parameter	Symbol	Min	Тур	Max	Unit	
DC Power Supplies	(Notes 21 and 22)					
	Positive Digital	VD+	-0.3	-	+6.0	V
	Positive Analog	VA+	-0.3	-	+6.0	V
Input Current, Any Pin Except Supplies	(Notes 23, 24, 25)	I _{IN}	-	-	±10	mA
Output Current, Any Pin Except VREFOUT		I _{OUT}	-	-	100	mA
Power Dissipation	(Note 26)	PD	-	-	500	mW
Analog Input Voltage	All Analog Pins	V_{INA}	- 0.3	-	(VA+) + 0.3	V
Digital Input Voltage	All Digital Pins	V _{IND}	-0.3	-	(VD+) + 0.3	V
Ambient Operating Temperature		T _A	-40	-	85	°C
Storage Temperature		T _{stg}	-65	-	150	°C

Notes: 21. VA+ and AGND must satisfy $[(VA+) - (AGND)] \le + 6.0 \text{ V}$.

- 22. VD+ and AGND must satisfy $[(VD+) (AGND)] \le + 6.0 \text{ V}.$
- 23. Applies to all pins including continuous over-voltage conditions at the analog input pins.
- 24. Transient current of up to 100 mA will not cause SCR latch-up.
- 25. Maximum DC input current for a power supply pin is ±50 mA.
- 26. Total power dissipation, including all input currents and output currents.

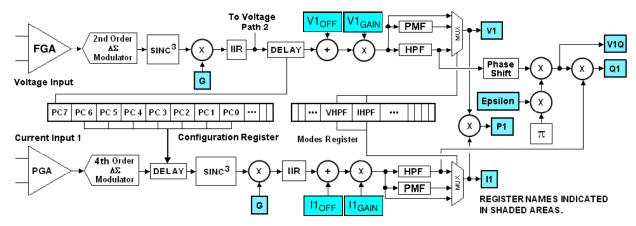


Figure 3. Signal Flow for V1, I1, P1, Q1 Measurements

4. SIGNAL PATH DESCRIPTION

The data flow for voltage and current measurement and the other calculations are shown in Figures 3, 4, and 5. The data flow consists of two current paths and two voltage paths. Both voltage paths are derived from the same differential input pins. Each current path has its own differential input pins.

4.1 Analog-to-Digital Converters

The voltage and temperature channels use second-order delta-sigma modulators and the two current channels use fourth-order delta-sigma modulators to convert the analog inputs to single-bit digital data streams. The converters sample at a rate of DCLK/8. This high sampling provides a wide dynamic range and simplifies anti-alias filter design.

4.2 Decimation Filters

The single-bit modulator output data is widened to 24 bits and down-sampled to DCLK/1024 with low-pass

decimation filters. These decimation filters are third-order Sinc. Their outputs are passed through third-order IIR "anti-sinc" filters, used to compensate for the amplitude roll-off of the decimation filters.

4.3 Phase Compensation

Phase compensation changes the phase of current relative to voltage by changing the sampling time in the decimation filters. The amount of phase shift is set by bits PC[7:0] in the Configuration register (*Config*) for channel 1 and bits PC[7:0] in the Control register (*Ctrl*) for channel 2.

Phase compensation, PC[7:0] is a signed two's complement binary value in the range of -1.0 to almost +1.0 output word rate (OWR) samples. For a sample rate of 4000 Hz, the delay range is $\pm 250~\mu S$, a phase shift of $\pm 4.5^{\circ}$ at 50 Hz and $\pm 5.4^{\circ}$ at 60 Hz. The step size would be 0.0352° at 50 Hz and 0.0422° at 60 Hz at this sample rate.

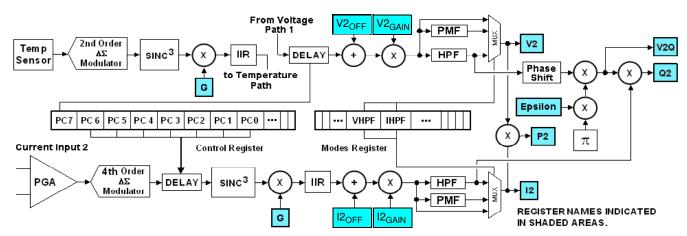


Figure 4. Signal Flow for V2, I2, P2, Q2 Measurements



4.4 DC Offset and Gain Correction

The system and chip inherently have gain and offset errors which can be removed using the gain and offset registers. (See Section 9. System Calibration on page 39). Each measurement channel has its own registers. For every channel, the output of the IIR filter is added to the offset register and multiplied by the gain register.

4.5 High-pass Filters

Optional high-pass filters (HPF in Figures 3 and 4) remove any DC from the selected signal paths. Subsequently, DC will also be removed from power, and all low-rate results. (see Figures 5).

Each energy channel has a current and voltage path. If an HPF is enabled in only one path, a phase-matching filter (PMF) is applied to the other path which matches the amplitude and phase delay of the HPF in the band of interest, but passes DC. For more information, see 6.5 *High-pass Filters* on page 19. The HPF filter multiplexers drive the *I1*, *V1*, *I2*, and *V2* result registers.

4.6 Low-Rate Calculations

Low-rate results are derived from sample-rate results integrated over N samples, where N is the value stored in the Cycle Count register. The low-rate interval is the sample interval multiplied by N.

4.7 RMS Results

The root mean square (*RMS* in Figure 5) calculations are performed on *N* instantaneous voltage and current samples, using the formula:

$$I_{RMS} = \sqrt{\frac{\sum_{n=0}^{N-1} I_n^2}{N}}$$



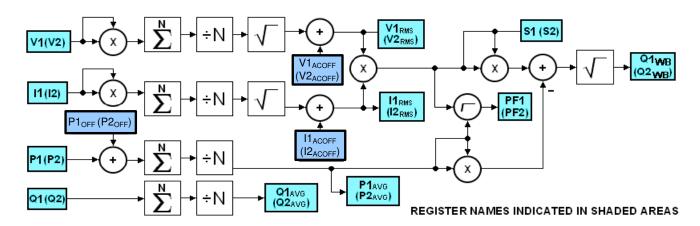


Figure 5. Low-rate Calculations

4.8 Power and Energy Results

The instantaneous voltage and current samples are multiplied to obtain the instantaneous power (P1, P2) (see Figure 3 and 4). The product is then averaged over N conversions to compute active power ($P1_{AVG}$, $P2_{AVG}$).

Apparent power (S1, S2) is the product of RMS voltage and current as shown:

$$S = V_{RMS} \times I_{RMS}$$

Power factor (*PF1*, *PF2*) is active power divided by apparent power as shown below. The sign of the power factor is determined by the active power.

$$PF = \frac{P_{ACTIVE}}{S}$$

Wideband reactive power ($Q1_{WB}$, $Q2_{WB}$) is calculated by doing a vector subtraction of active power from apparent power.

$$Q_{WB} = \sqrt{S^2 - P_{ACTIVE}^2}$$

Quadrature power (Q1, Q2) are sample rate results obtained by multiplying instantaneous current (I1, I2) by instantaneous quadrature voltage (V1Q, V2Q) which are created by phase shifting instantaneous voltage (V1, V2) 90 degrees using first-order integrators. (see Figure 3 and 4). The gain of these integrators is inversely relat-

ed to line frequency, so their gain is corrected by the *Epsilon* register, which is based on line frequency.

Reactive power ($Q1_{AVG}$, $Q2_{AVG}$) is generated by integrating the instantaneous quadrature power over N samples.

4.9 Peak Voltage and Current

Peak current ($I1_{PEAK}$, $I2_{PEAK}$) and peak voltage ($V1_{PEAK}$, $V2_{PEAK}$) are the largest current and voltage samples detected in the previous low-rate interval.

4.10 Power Offset

The power offset registers, $P1_{OFF}$ ($P2_{OFF}$) can be used to offset erroneous power sources resident in the system not originating from the power line. Residual power offsets are usually caused by crosstalk into current paths from voltage paths or from ripple on the meter or chip's power supply, or from inductance from a nearby transformer.

These offsets can be either positive or negative, indicating crosstalk coupling either in phase or out of phase with the applied voltage input. The power offset registers can compensate for either condition.

To use this feature, measure the average power at no load using either Single or Continuous Conversion commands. Take the measured result (from the $P1_{AVG}$ ($P2_{AVG}$) register), invert (negate) the value and write it to the associated power offset register, $P1_{OFF}$ ($P2_{OFF}$).



5. PIN DESCRIPTIONS

5.1 Analog Pins

The CS5464 has three differential inputs: VIN \pm , IIN1 \pm , and IIN2 \pm are the voltage, current1, and current2 inputs, respectively. A single-ended power fail monitor input, voltage reference input, and voltage reference output are also available.

5.1.1 Voltage Inputs

The output of the line voltage resistive divider or transformer is connected to the VIN+ and VIN- input pins of the CS5464. The voltage channel is equipped with a 10x, fixed-gain amplifier. The full-scale signal level that can be applied to the voltage channel is ± 250 mV. If the input signal is a sine wave, the maximum RMS voltage is 250mVp / $\sqrt{2} \approx 176.78$ mVRMS which is approximately 70.7% of maximum peak voltage.

5.1.2 Current1 and Current2 Inputs

The output of the current-sensing resistor or transformer is connected to the IIN1+ (IIN2+) and IIN1- (IIN2-) input pins of the CS5464. To accommodate different current-sensing elements, the current channel incorporates a programmable gain amplifier (PGA) with two selectable input gains. The full-scale signal level for the current channels is ±50mV or ±250mV. If the input signal is a sine wave, the maximum RMS voltage is 35.35mVRMS or 176.78mVRMS which is approximately 70.7% of maximum peak voltage.

5.1.3 Power Fail Monitor Input

An analog input (PFMON) is provided to determine when a power loss is imminent. By connecting a resistive divider from the unregulated meter power supply to the PFMON input, an interrupt can be generated, or the Low Supply Detected (LSD) *Status* register bit can be monitored to indicate low-supply conditions. The PFMON input has a comparator that trips around the level of the voltage reference input (VREFIN).

5.1.4 Voltage Reference Input

The CS5464 requires a stable voltage reference of 2.5 V applied to the VREFIN pin. This reference can be supplied from an external voltage reference or from the VREFOUT output. A bypass capacitor of at least 0.1 μF is recommended at the VREFIN pin.

5.1.5 Voltage Reference Output

The CS5464 generates a 2.5 V reference (VREFOUT). It is suitable for driving the VREFIN pin, but has very little fan-out and is not recommended for driving external circuits.

5.1.6 Crystal Oscillator

An external quartz crystal can be connected to the XIN and XOUT pins as shown in Figure 6. To reduce system cost, each pin is supplied with an on-chip, phase-shifting capacitor to ground.

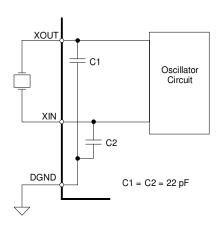


Figure 6. Oscillator Connections

Alternatively, an external clock source can be connected to the XIN pin.

5.2 Digital Pins

5.2.1 Reset Input

The active-low RESET pin, when asserted, will halt all CS5464 operations and reset internal hardware registers and states. When de-asserted, an initialization sequence begins, setting default register values.

5.2.2 CPU Clock Output

A logic-level clock output (CPUCLK) is provided at the crystal frequency to drive an external CPU or microcontroller clock. Two phase choices are available.

5.2.3 Interrupt Output

The INT pin indicates an enabled Internal Status register (*Status*) bit is set. *Status* register bits indicate conditions such as data ready, modulator oscillations, low supply, voltage sag, current faults, numerical overflows, and result updates.

5.2.4 Energy Pulse Outputs

The CS5464 provides three pins $(\overline{E1}, \overline{E2}, \overline{E3})$ for pulse energy outputs. These pins can also be used to output other conditions, such as voltage sign, power fail monitor, or energy channel in use.



5.2.5 Serial Interface

The CS5464 provides 5 pins, SCLK, SDI, SDO, \overline{CS} , and MODE for communication between a host microcontroller or serial E²PROM and the CS5464.

MODE is an input that, when high, indicates to the CS5464 that a serial E²PROM is being used instead of a host microcontroller. It has a weak pull-down allowing it to be left unconnected if microcontroller mode is used.

SCLK is used to shift and qualify serial data. Serial data changes as a result of the falling edge of SCLK and is valid during the rising edge. It is a Schmitt-trigger input

for host microcontrollers, and a driven output for serial E²PROMs.

SDI is the serial data input to the CS5464.

SDO is the serial data output from the CS5464. It's output drivers are disabled whenever CS is de-asserted, allowing other devices to drive the SDO line.

CS is the chip select input for the serial bus. A high logic level de-asserts it, tri-stating the SDO pin and clearing the serial interface. A low logic level enables the serial port. This pin may be tied low for systems not requiring multiple SDO drivers. CS is a driven output when interfacing to serial E²PROMs.



6. SETTING UP THE CS5464

6.1 Clock Divider

The internal clock to the CS5464 needs to operate around 4 MHz. However, by using the internal clock divider, a higher crystal frequency can be used. This is important when driving an external microcontroller requiring a faster clock and using the CPUCLK output.

K is the divide ratio from the crystal input to the internal clock and is selected with Configuration register (*Config*) bits K[3:0]. It has a range of 1 to 16. A value of zero results in a setting of 16.

6.2 CPU Clock Inversion

By default, CPUCLK is inverted from XIN. Setting Configuration register bit iCPU removes this inversion. This can be useful when one phase adds more noise to the system than the other.

6.3 Interrupt Pin Behavior

The behavior of the $\overline{\text{INT}}$ pin is controlled by the IMODE and IINV bits in the Configuration register as shown.

IMODE	IINV	INT Pin		
0	0	Active-low Level		
0	1	Active-high Level		
1	0	Low Pulse		
1	1	High Pulse	7	

Table 1. Interrupt Configuration

If IMODE = 1, the duration of the $\overline{\text{INT}}$ pulse will be two DCLK cycles, where DCLK = MCLK/K.

6.4 Current Input Gain Ranges

Control register bits I1gain (I2gain) select the input range of the current inputs.

l1gain, l2gain	Maximum Input	Gain	
0	±250 mV	10x	
1	±50 mV	50x	

Table 2. Current Input Gain Ranges

6.5 High-pass Filters

Mode Control (*Modes*) register bits VHPF and IHPF activate the HPF in the voltage and current paths, respectively. Each energy channel has separate VHPF and IHPF bits. When a high-pass filter is enabled in only one

path within a channel, a phase matching filter (PMF) is applied to the other path within that channel. The PMF filter matches the amplitude and phase response of the HPF in the band of interest, but passes DC.

VHPF	IHPF	Filter Configuration
0	0	No filter on Voltage or Current
0	1	HPF on Current, PMF on Voltage
1	0	HPF on Voltage, PMF on Current
1	1	HPF on Current and Voltage

Table 3. High-pass Filter Configuration

6.6 Cycle Count

Low-rate calculations, such as average power and RMS voltage and current integrate over several (*N*) output word rate (OWR) samples. The duration of this averaging window is set by the Cycle Count (*N*) register. By default, Cycle Count is set to 4000 (1 second at output word rate [OWR] of 4000 Hz). The minimum value for Cycle Count is 10.

6.7 Energy Pulse Outputs

By defa<u>ult</u>, E1 outputs active energy, E3, reactive energy, and E2, the sign of both active and reactive energy. (See Figure 2. *Timing Diagram for E1, E2, and E3* on page 13.)

Three pairs of bits in the Mode Control (*Modes*) register control the operation of these outputs. These bits are named E1MODE[1:0], E2MODE[1:0], and E3MODE[1:0]. Some combinations of these bits override others, so read the following paragraphs carefully.

The E2 pin can output energy sign, apparent energy, or energy <u>channel</u> in use (1 or 2). Table 4 lists the functions of E2 as controlled by E2MODE[1:0] in the *Modes* register.

Note: E2MODE[1:0]=3 is a special mode.

E2MODE1	E2MODE0	E2 output		
0 0		Energy Sign		
0	1	Apparent Energy		
1	0	Channel in Use		
1	1	Enable E1MODE		

Table 4. E2 Pin Configuration

The $\overline{E3}$ pin can output reactive energy, power fail monitor status, voltage sign, or apparent energy. Table 5



lists the functions of $\overline{E3}$ as controlled by E3MODE[1:0] in the *Modes* register when E1MODE is not enabled.

E3MODE1	E3MODE0	E3 output		
0	0	Reactive Energy		
0	1	Power Fail Monitor		
1	0	Voltage Sign		
1	1	Apparent Energy		

Table 5. E3 Pin Configuration

When both E2MODE bits are high, the E1MODE bits are enabled, allowing active, apparent, reactive, or wideband reactive energy for **both** energy channels to be output on E1 and E2. Table 6 lists the functions of E1 and E2 with E1MODE enabled.

E1MODE1	E1MODE0	E1 / E2 outputs		
0	0	Active Energy		
0	1	Apparent Energy		
1	0	Reactive Energy		
1	1	Wideband Reactive		

Table 6. E1 / E2 Modes

When E1MODE bits are enabled, the $\overline{E3}$ pin outputs either the power fail monitor status, or the sign of the $\overline{E1}$ and $\overline{E2}$ outputs. Table 7 list the functions of the $\overline{E3}$ pin using E3MODE[1:0] in the *Modes* register when E1MODE is enabled.

E3MODE1	E3MODE0	E3 output
0	0	Power Fail Monitor
0	1	Energy Sign
1	0	not used
1 1		not used

Table 7. E3 Pin with E1MODE enabled

6.8 No Load Threshold

The No Load Threshold register ($Load_{MIN}$) is used to zero out the contents of E_{PULSE} and Q_{PULSE} registers if their magnitude is less than the $Load_{MIN}$ register value.

6.9 Energy Pulse Width

Note: Energy Pulse Width (*PulseWidth*) only applies to E1, E2, or E3 pins that are configured to output pulses. When any are configured to output steady-state signals, such as voltage sign, energy channel in use, power fail monitor, or energy sign, pulse widths and output rates do not apply.

The pulse width time (t_{pw}) in Figure 2, is set by the value in the *PulseWidth* register which is an integer multiple of the sample or output word rate (OWR). At OWR of 4000 Hz (a period of 250 uS) $t_{pw} = PulseWidth \times 250$ uS. By default, *PulseWidth* is set to 1.

6.10 Energy Pulse Rate

The full-scale pulse frequency of enabled $\overline{E1}$, $\overline{E2}$, $\overline{E3}$ pins is the *PulseRate* x output word rate (OWR)/2. The actual pulse frequency is the full-scale pulse frequency multiplied by the pulse register's (E_{PULSE} , S_{PULSE} , Q_{PULSE}) value.

Example:

If the output word rate (OWR) is 4000 Hz, and the *PulseRate* is set to 0.05, the full-rate pulse frequency is $0.05 \times 4000 / 2 = 100$ Hz. If the E_{PULSE} register, driving $\overline{E1}$, is 0.4567, the pulse output rate on $\overline{E1}$ will be $100 \text{ Hz} \times 0.4567 = 45.67 \text{ Hz}$.

6.11 Voltage Sag/Current Fault Detection

Voltage sag detection is used to determine when averaged voltage falls below a predetermined level for a specified interval of time. Current fault detection determines when averaged current falls below a predetermined level for a specified interval of time.

The specified interval of time (duration) is set by the value in the $V1Sag_{DUR}$ ($V2Sag_{DUR}$) and $I1Fault_{DUR}$ ($I2Fault_{DUR}$) registers. Setting any of these to zero (default) disables the detect feature for the given channel. The value is in output word rate (OWR) samples. The predetermined level is set by the values in the $V1Sag_{LEVEL}$ ($V2Sag_{LEVEL}$) and $I1Fault_{LEVEL}$ ($I2Fault_{LEVEL}$) registers.

Since the values of *V1* and *V2* come from the same input, only one voltage sag detector is necessary.



For each enabled input channel, the measured value is rectified and compared to the associated level register. Over the duration window, the number of samples above and below the level are counted. If the number of samples below the level exceeds the number of samples above, a *Status* register bit V1_{SAG} (V2_{SAG}), I1_{FAULT} (I2_{FAULT}) is set, indicating a sag or fault condition. (see Figure 7)..

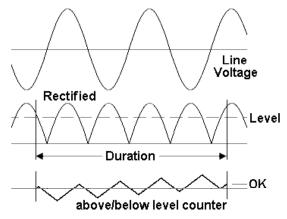


Figure 7. Sag and Fault Detect

6.12 Epsilon

The *Epsilon* register is used to set the gain of the 90° phase shift used in the quadrature power calculation.

The value in the *Epsilon* register is the ratio of the line frequency to the output word rate (OWR). It is, by default, 50/4000 (0.0125), for 50 Hz line and 4000 Hz sample (OWR) frequencies.

For 60 Hz line frequency, it is 60/4000 (0.015). Other output word rates (OWR) can be used.

Epsilon can also be calculated automatically by the CS5464 by setting the AFC bit in the Mode Control (*Modes*) register. The Frequency Update bit (FUP) in the *Status* register is set every time the *Epsilon* register has been automatically updated.

6.13 Temperature Measurement

The on-chip temperature sensor is designed to measure temperature and optionally compensate for temperature drift of the voltage reference. It uses the VBE of a transistor to determine temperature.

Temperature measurements are stored in the Temperature register (*T*) which, by default, is configured to a range of ±128 degrees on the Celsius (°C) scale.

The application program can change both the scale and range of Temperature (T) by changing the Temperature Gain ($T_{GA/N}$) and Temperature Offset (T_{OFF}) registers.

Two values must be known — the transistor's ΔVBE per degree, and the transistor's VBE at 0 degrees. At the time of this publication, these values are:

 Δ VBE (per degree) = 0.2769523 mV/°C or °K

 $V_{BE}0 = 79.2604368 \text{ mV at } 0^{\circ}\text{C}$

To determine the values to write to T_{GAIN} and T_{OFF} , use the following formulae:

$$T_{GAIN} = AD_{FS} / \Delta VBE / T_{FS} \times 2^{17}$$

 $T_{OFF} = -V_{BE}0 / AD_{FS} \times 2^{23}$

In the above equations, AD_{FS} is the full-scale input range of the temperature A/D converter or 833.333 mV and T_{FS} is the desired full-scale range of the Temperature register. The binary exponents are the bit positions of the binary point of these registers.

To use the Celsius scale (°C) and cover the chip's operating temperature range of -40°C to +85°C, the Temperature register range needs to be ± 128 degrees. T_{FS} should be 128 degrees.

 $T_{GAIN} = 833.333 / 0.2769523 / 128 \times 131072$

= 3081155 (0x2F03C3)

 $T_{OFF} = -79.2604368 / 833.333 \times 8388608$

= -797862 (0xF3D35A)

These are the actual default values for these registers.

 T_{GAIN} and T_{OFF} can also be used to calibrate the gain and/or offset of the temperature sensor or A/D converter. (See Section 9. *System Calibration* on page 39).

To use the Kelvin (°K) scale, simply add 273 times $\Delta VBE / AD_{FS} \times 2^{23}$ to T_{OFF} since 0°C = 273°K,. You will also need more range. Since -40°C to +85°C is 233°K to 358°K, a T_{FS} of 512 degrees should be used in the T_{GAIN} calculation.

To use the Fahrenheit (°F) scale, multiply Δ VBE by 5/9 and add 32 times the new Δ VBE / AD_{FS} x 2²³ to T_{OFF} since 0°C = 32°F. You will also want to use a T_{FS} of 256 degrees to cover the -40°C to +85°C range.

The Temperature register (*T*) updates every 2240 output word rate (OWR) samples. The *Status* register bit TUP indicates when *T* is updated.



7. USING THE CS5464

7.1 Initialization

The CS5464 uses a power-on-reset circuit (POR) to provide an internal reset until the analog voltage reaches 4.0 V. The RESET input pin can also be used by the application circuit to reset the part.

After RESET is removed and the oscillator is stable, an initialization program is executed to set the default register values.

A Software Reset command is also provided to allow the application to run the initialization program without removing power or asserting RESET.

The application should avoid sending commands during initialization. The DRDY bit in the *Status* register indicates when the initialization program has completed.

7.2 Power-down States

The CS5464 has two power-down states, stand-by and sleep. In the stand-by state, all circuitry except the voltage reference and crystal oscillator is powered off. In sleep state, all circuitry except the instruction decoder is powered off.

To return the device to the active state, send a Wake-Up/Halt command to the device. When returning from stand-by mode, registers will retain their contents prior to entering the stand-by state. When returning from sleep mode, a complete initialization occurs.

7.3 Tamper Detection and Correction

The CS5464 provides compensation for at least two forms of meter tampering. A second current input is provided in the event that the primary input is impaired by tampering. (See Figure 14 on page 42). An internal RMS voltage reference is also available in the event that the voltage input has been compromised by tampering. Power and energy are calculated for BOTH current inputs (both energy channels). The CS5464 can automatically choose the channel with the greater magnitude. The register E_{MIN} , (also called $Irms_{MIN}$) sets a minimum level for automatic channel selection, and $Ichan_{LEVEL}$ sets a minimum difference that will allow a channel

change. *Modes* register bit Ichan selects the energy channel, and is normally driven by the CS5464 program. This affects the pulse registers and pulse energy outputs. (See figure 8).

The application program can also choose the more appropriate energy channel. *Modes* register bit Ihold disables automatic selection and Ichan can be driven by the application. Shown below is the channel selector.

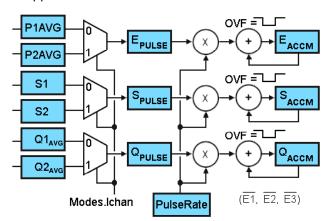


Figure 8. Energy Channel Selection

If the application detects that the voltage input has been impaired it may choose to use the fixed internal RMS voltage reference by setting the VFIX bit in the *Modes* register. The value of this reference (VF_{RMS}) is by default 0.707107 (full-scale RMS) but can be changed by the application program. (See figure 9)

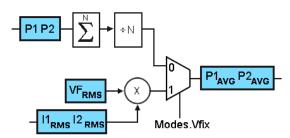


Figure 9. Fixed RMS Voltage Selection



7.4 Command Interface

Commands and data are transferred most-significant bit (MSB) first. Figure 1 on page 12, defines the serial port timing. Commands are clocked in on SDI using SCLK. They are a single byte (8 bits) long and fall into one of four basic types:

- 1. Register Read
- 2. Register Write
- 3. Synchronizing
- 4. Instructions

Register reads will cause up to four bytes of register data to be clocked out, MSB first on the SDO pin by SCLK. During this time, other commands can be clocked in on the SDI pin. Other commands will not interrupt read data, except another register read, which will cause the new read data to appear on SDO.

Synchronizing can be sent while read data is being clocked out if no other commands need to be sent.

Synchronizing commands are also used to synchronize the serial port to a byte boundary. The CS and RESET pins will also synchronize the serial port.

Register writes require three bytes of write data to follow, clocked in on the SDI pin, MSB first by SCLK.

Instructions are commands that will interrupt any instruction currently executing and begin the new instruction. These include conversions, calibrations, power control, and soft reset.

(See Section 7.6 Commands on page 24).

7.5 Register Paging

Read and Write commands access one of 32 registers within a specified page. The Resgister Page Select register's (*Page*) default value is 0. To access registers in another page, write the desired page number to the *Page* register. The *Page* register is always at address 31 and is accessible from within any page.



7.6 Commands

All commands are 1 byte (8 bits) long. Many command values are unused and should NOT be written by the application program. All commands except register reads, register writes, or synchronizing commands will abort any conversion, calibration, or any initialization sequence currently executing. This includes reset. No commands other than reads or synchronizing should be executed until the reset sequence completes.

7.6.1 Conversion

B7	B6	B5	B4	B3	B2	B1	B0
1	1	1	0	CC	0	0	0

Executes a conversion (measurement) program.

CC Continuous/Single Conversion

0 = Perform a Single Conversion (0xE0) 1 = Perform Continuous Conversion (0xE8)

7.6.2 Synchronization (SYNC0 and SYNC1)

B7	B6	B5	B4	B 3	B2	B1	B0
1	1	1	1	1	1	1	SYNC

The serial interface is bidirectional. While reading data on the SDO output, the SDI input must be receiving commands. If no command is needed during a read, SYNC0 or SYNC1 commands can be sent while read data is received on SDO.

The serial port is normally initialized by de-asserting \overline{CS} . An alternative method of initialization is to send 3 or more SYNC1 commands followed by a SYNC0. This is useful in systems where \overline{CS} is not used and tied low.

7.6.3 Power Control (Stand-by, Sleep, Wake-up/Halt and Software Reset)

	B7	B6	B5	B4	B 3	B2	B1	B0
ſ	1	0	S1	S0	0	0	0	0

The CS5464 has two power-down states, stand-by and sleep. In stand-by, all circuitry except the voltage reference and clocks are turned off. In sleep, all circuitry except the command decoder is turned off. A Wake-up/Halt command restores full-power operation after stand-by and issues a hardware reset after sleep. The Software Reset command is a program that emulates a pin reset and is not a power control function.

S[1:0] 00 = Software Reset

01 = Sleep

10 = Wake-up/Halt

11 = Stand-by



7.6.4 Calibration

B7	B 6	B5	B4	B 3	B2	B1	B0
1	0	CAL5	CAL4	CAL3	CAL2	CAL1	CAL0

The CS5464 can perform gain and offset calibrations using either DC or AC signals. Proper input levels must be applied to the current inputs and voltage input before performing calibrations.

 $CAL[5:4]^*$ 00 = DC Offset

01 = DC Gain 10 = AC Offset 11 = AC Gain

CAL[3:0] 0001 = Current for Channel 1

0010 = Voltage for Channel 1 0100 = Current for Channel 2 1000 = Voltage for Channel 2

Note: Anywhere from 1 to all 4 channels can be calibrated simultaneously. Voltage channels 1 and 2

use the same voltage input. Commands with CAL[5:0] = 0 are not calibrations.